

isc N-Channel MOSFET Transistor

DMG3N60SJ3

FEATURES

- Drain Current –I_D= 2.8A@ T_C=25 $^\circ\!\mathrm{C}$
- Drain Source Voltage : V_{DSS}= 600V(Min)
- Static Drain-Source On-Resistance
- : R_{DS(on)} = 350m Ω (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

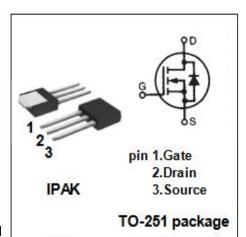
• Designed for use in switch mode power supplies and general purpose applications.

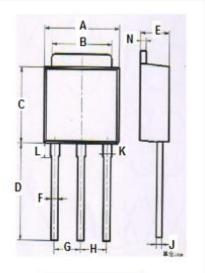
ABSOLUTE MAXIMUM RATINGS(Ta=25 C)						
SYMBOL	PARAMETER	VALUE	UNIT			
V _{DSS}	Drain-Source Voltage	600	V			
V _{GS}	Gate-Source Voltage-Continuous	±30	V			
ID	Drain Current-Continuous	2.8	A			
I _{DM}	Drain Current-Single Pluse	4.2	А			
P _D	Total Dissipation @Tc=25℃	41	W			
TJ	Max. Operating Junction Temperature	-55~150	°C			
T _{stg}	Storage Temperature	-55~150	°C			

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	3.0	℃ /W





	mm	
DIM	MIN	MAX
Α	6.40	6.48
В	5.10	5.50
С	5.80	6.20
D	9.20	9.60
Ε	2.20	2.40
F	0.50	0.70
G	2.09	2.49
H	2.09	2.49
J	0.40	0.60
Κ	0.70	0.90
L	1.60	2.00
N	0.40	0.60

isc website: www.iscsemi.com



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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25\,^{\circ}\!\!\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 0.25mA	600		V
V _{GS(th)}	Gate Threshold Voltage	V_{DS} = V_{GS} ; I_D = 0.25mA	2.0	4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 1.5A		350	mΩ
lgss	Gate-Body Leakage Current	V _{GS} = ±30V;V _{DS} = 0		±100	nA
ldss	Zero Gate Voltage Drain Current	V _{DS} = 600V; V _{GS} = 0		1.0	μA
V _{SD}	Forward On-Voltage	I _S = 3.0A; V _{GS} = 0		1.5	V

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